

Product data sheet

1. General description

AC Thyristor power switch in a SOT54 plastic package with self-protective capabilities against low and high energy transients

2. Features and benefits

- Exclusive negative gate triggering •
- Full cycle AC conduction
- High noise immunity •
- Remote gate separates the gate driver from the effects of the load current •
- Very sensitive gate for lowest gate trigger current
- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients •

3. Applications

- Fan motor circuits •
- Pump motor circuits
- Lower-power highly inductive, resistive and safety loads •

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 71 °C; <u>Fig. 1</u>	-	-	0.8	А
Static chara	acteristics		·			
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA

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5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	СМ	common		LD				
2	G gate							
3	LD	load	321 TO-92 (SOT54)	G —• □[́_ ↓ CM 001aaj924				

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
ACT108-600D	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
ACT108-600D/DG	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

ACT108-600D

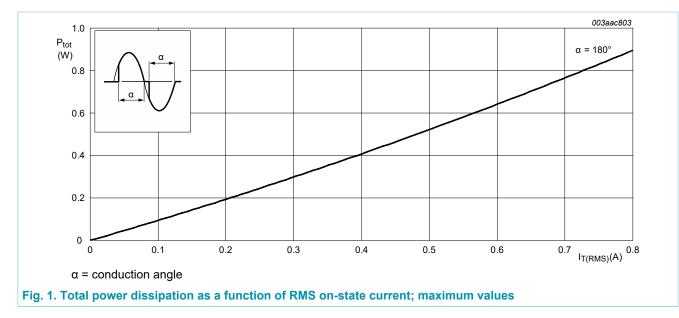
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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

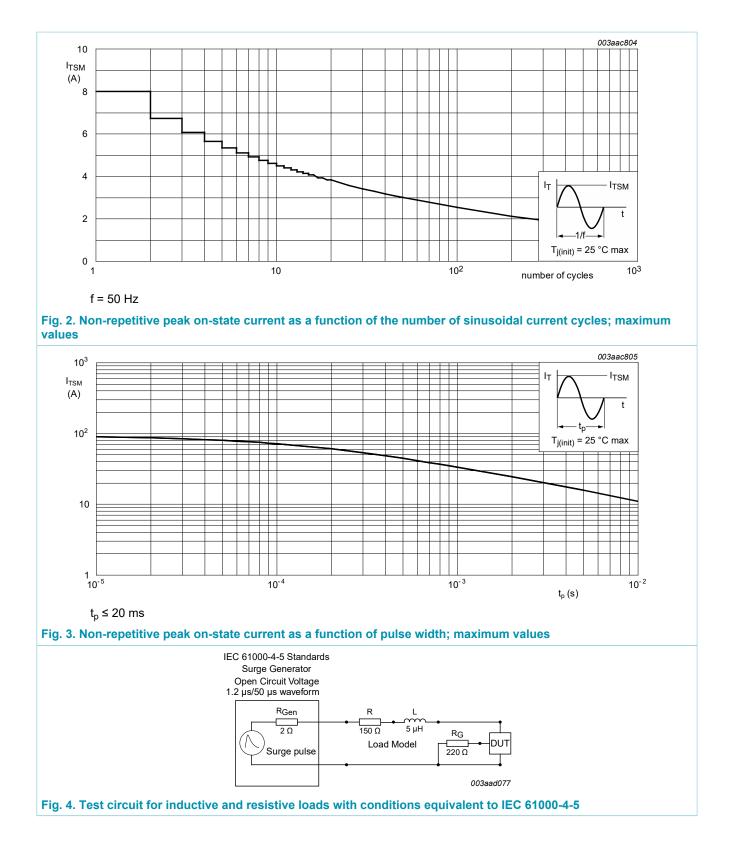
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 71 °C; <u>Fig. 1</u>	-	0.8	А
I _{TSM}	non-repetitive peak on-	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	8.8	А
	state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 2; Fig. 3	-	8	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A²s
dl _T /dt	rate of rise of on-state current	I _G = 10 mA	-	50	A/µs
I _{GM}	peak gate current	t = 20 µs	-	1	А
V _{GM}	peak gate voltage		-	15	V
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; <u>Fig. 4</u>	-	2	kV



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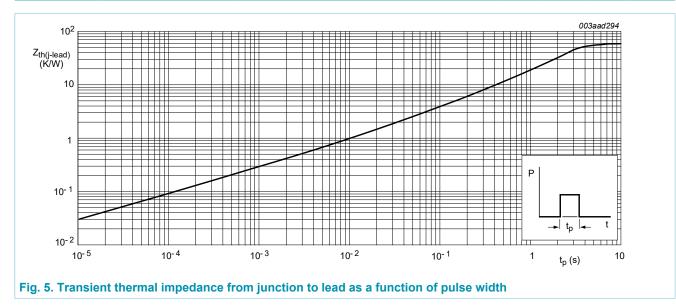
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8. Thermal characteristics

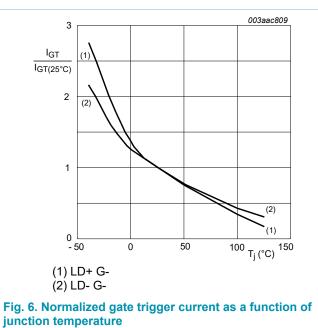
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle with heatsink compound; Fig. 5	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	full cycle; printed-circuit board mounted; lead length 4 mm	-	150	-	K/W

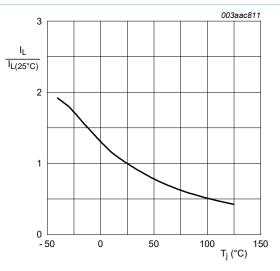


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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 6</u>	0.5	-	5	mA
IL	latching current	V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	25	mA
		V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	25	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 8</u>	-	-	20	mA
V _T	on-state voltage	I _T = 1.1 A; T _j = 25 °C; <u>Fig. 9</u>	-	-	1.3	V
V _{GT}	gate trigger voltage	V _D = 400 V; I _T = 100 mA; T _j = 125 °C	0.15	-	-	V
		V _D = 12 V; I _T = 100 mA; T _j = 25 °C	-	-	0.9	V
I _D	off-state current	V _D = 600 V; T _j = 25 °C	-	-	2	μA
		V _D = 600 V; T _j = 125 °C	-	-	0.2	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j ≤ 125 °C	650	-	-	V
Dynamic ch	narateristics			1		
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 10	300	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 1 \text{ A};$ $dV_{com}/dt = 15 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ Fig. 11; Fig. 12	0.15	-	-	A/ms





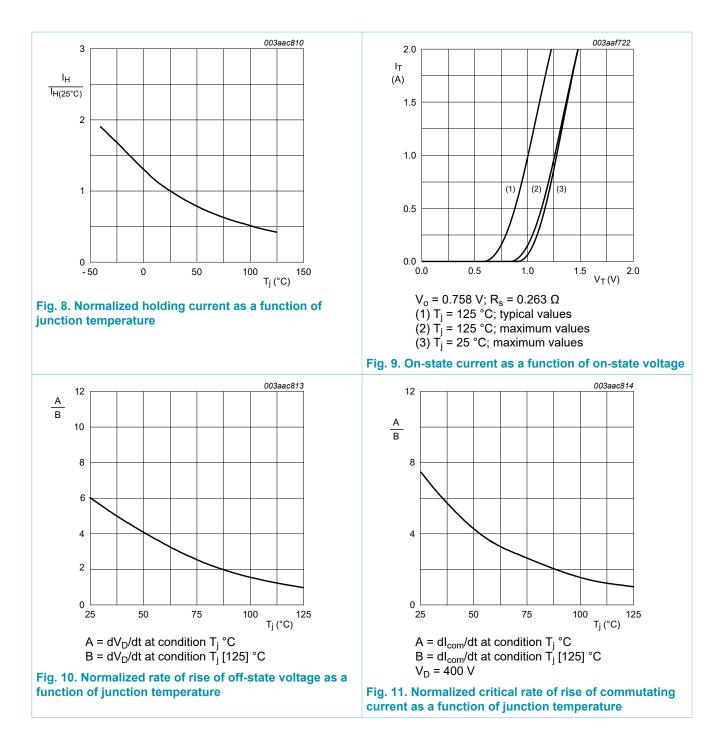


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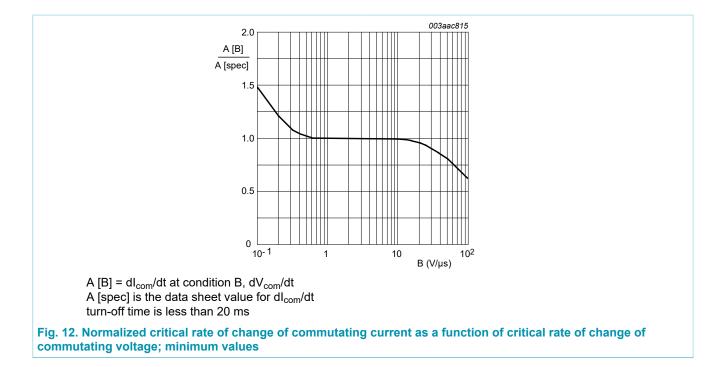
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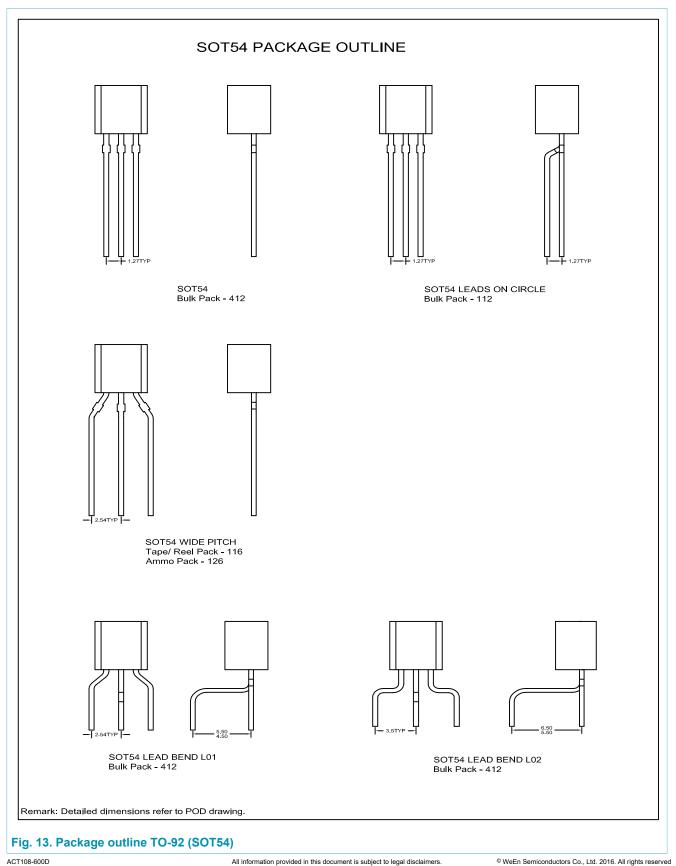
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10. Package outline



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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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